## nexperia

## **Quarterly Reliability Monitoring Results**

Quarters: Q1/2022 to Q4/2023

Based on structural similarity

Supplier		User Part Number					
Nexperia B.V.		PNU65020EP					
Name of Laboratory Assembly reliability labs Test		Part Description					
		Nexperia DHAM	Rectifier				
		SMD package					
		Test Conditions	Duration	# Lots	# Quantity	# Rejects	
	TEST						
	Pre- and Post-Stress						
# 1	Electrical Test	Tamb = 25 °C	N/A	see below	all parts	see below	
		JESD22-A113					
		Bake Tamb = 125 °C	24 hours				
# <b>2</b>	PC Preconditioning	Soak Tamb = 85 °C, RH = 85% Reflow soldering	168 hours 3 cycles	1514	64420	0	
# 2	reconditioning	-	J CYCIES	1514	64430	0	
	UTDP	MIL-STD-750-1					
	HTRB High Temperature Reverse	M1038 Method A Tj = Tjmax, Vr = 100% of max. datasheet					
# 5	Bias	reverse voltage	1000 hours	40	1840	0	
# <b>J</b>			1000 110013	-10	1040	0	
	тс	JESD22-A104					
# 7	Temperature Cycling	-65 °C to Tjmax, not to exceed 150°C	500 cycles	311	14080	0	
			,				
	UHAST	JESD22-A118					
# 8 <b>or</b>	Unbiased HAST	Tamb = 130 °C, RH = 85 %	— 96 hours	311	14080	0	
		JESD22-A102	96 nours				
	AC	Tamb = 121 °C, RH = 100 %					
# 8a	Autoclave	Pressure = 205 kPa (29.7 psia)					
	H3TRB	JESD22-A101					
	High Humidity High	Tamb = 85 °C, RH = 85%, VR = 80 % of					
# 9	Temperature Reverse Bias	rated reverse voltage <sup>[1]</sup>	1000 hours	311	14080	0	
		MIL-STD-750 Method 1037					
	IOL	ton = toff, devices powered to insure $\Delta T j = 100.00$					
# 10	Intermittent Operating Life	100 °C	333 hours	312	14120	0	
	DCU	155532 4111					
# 20	<b>RSH</b> Resistance to Solder Heat	JESD22-A111 260 °C ± 5 °C	10 -	260	0070	0	
# 20		200 C ± 3 °C	10 s	269	8070	0	
# 21	<b>SD</b> Solderability	J-STD-002		222	6660	0	
+ Z1	Solderability	5 515 002		222	0000	U	

[1] The maximum applied voltage is limited by test chamber set up and does not exceed 115V.

## **Calculation of FIT and MTTF**

Test considered for FIT calculation: High Temperature Reverse Bias (HTRB, Test # 5) Confidence level 60%, derated to 55 °C, activation energy 0.7 eV, test time 168 to 1000 hours

Wafer Fab	Technology	Quantity	Rejects	Failure Rate (FIT)	MTTF (hrs)
Nexperia					
DHAM	Rectifier	1840	0	2,31	4,33E+08

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